LOW-QUIESCENT-CURRENT PROGRAMMABLE-DELAY SUPERVISORY CIRCUIT

Check for Samples: TPS3808-Q1

FEATURES

- **Qualified for Automotive Applications**
- **Power-On Reset Generator With Adjustable Delay Time: 1.25 ms to 10 s**
- **Very Low Quiescent Current: 2.4 µA Typ**
- **High Threshold Accuracy: 0.5% Typ**
- **Fixed Threshold Voltages for Standard Voltage Rails From 1.2 V to 5 V and Adjustable Voltage Down to 0.4 V Are Available**
- **Manual Reset ($\overline{MR}$) Input**
- **Open-Drain $\overline{RESET}$ Output**
- **Temperature Range: –40°C to 125°C**
- **Small SOT-23 Package**

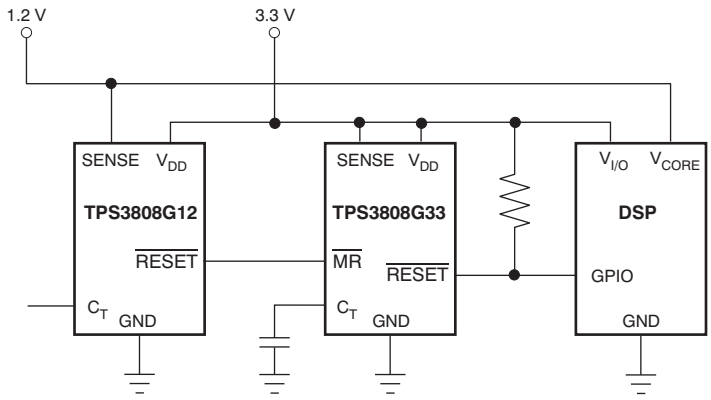
APPLICATIONS

- **DSP or Microcontroller Applications**
- **Notebook/Desktop Computers**
- **PDAs/Hand-Held Products**
- **Portable/Battery-Powered Products**
- **FPGA/ASIC Applications**

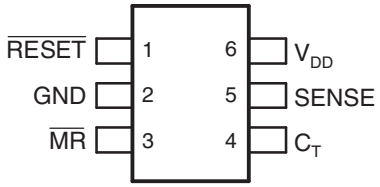
DESCRIPTION

The TPS3808 microprocessor supervisory circuits monitor system voltages from 0.4 V to 5 V, asserting an open-drain $\overline{RESET}$ signal when the SENSE voltage drops below a preset threshold or when the manual reset ($\overline{MR}$) pin drops to a logic low. The $\overline{RESET}$ output remains low for the user-adjustable delay time after the SENSE voltage and $\overline{MR}$ return above their thresholds.

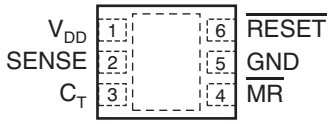
The TPS3808 uses a precision reference to achieve 0.5% threshold accuracy for $V_{IT} \leq 3.3$ V. The reset delay time can be set to 20 ms by disconnecting the C_T pin, 300 ms by connecting the C_T pin to V_{DD} using a resistor, or can be user adjusted between 1.25 ms and 10 s by connecting the C_T pin to an external capacitor. The TPS3808 has a very low typical quiescent current of 2.4 µA, so it is well suited to battery-powered applications. It is available in a small SOT-23 package and is fully specified over a temperature range of –40°C to 125°C (T_J).



DBV (SOT-23) PACKAGE
(TOP VIEW)



DRV PACKAGE
(TOP VIEW)



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION(1)

T_J	NOMINAL SUPPLY VOLTAGE	THRESHOLD VOLTAGE (V_{IT})	PACKAGE(2)		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 125°C	Adjustable	0.405 V	SON – DRV	Reel of 3000	TPS3808G01QDRVRQ1	PSJQ
			SOT-23 – DBV	Reel of 3000	TPS3808G01QDBVRQ1	BAZ
	1.25 V	1.16 V	SOT-23 – DBV	Reel of 3000	TPS3808G125QDBVRQ1	QWZ
	1.2 V	1.12 V			TPS3808G12QDBVRQ1	CEM
	1.5 V	1.4 V			TPS3808G15QDBVRQ1	OFR
	1.8 V	1.67 V			TPS3808G18QDBVRQ1	OBZ
	3 V	2.79 V			TPS3808G30QDBVRQ1	AVP
	3.3 V	3.07 V			TPS3808G33QDBVRQ1	AVQ
	5 V	4.65 V			TPS3808G50QDBVRQ1	CEL

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

ABSOLUTE MAXIMUM RATINGS

over operating junction temperature range (unless otherwise noted)(1)

V_{DD}	Input voltage range			–0.3 V to 7 V
V_{CT}	C_T voltage range			–0.3 V to (V_{DD} + 0.3) V
V_{MR}, V_{RESET}, V_{SENSE}	$\overline{MR}$, $\overline{RESET}$, SENSE voltage ranges			–0.3 V to 7 V
I_{RESET}	$\overline{RESET}$ pin current			5 mA
T_J	Operating junction temperature range(2)			–40°C to 150°C
T_{stg}	Storage temperature range			–65°C to 150°C
ESD	Electrostatic discharge rating	Human-Body Model (HBM)		2 kV
		Charged-Device Model (CDM)	TPS3808GXX	500 V
			TPS3808G125QDBVRQ1	1000 V
		Machine Model (MM), TPS3808G01QDRVRQ1,TPS3808G125QDBVRQ1		50 V

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under the *Electric Characteristics* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Due to the low dissipated power in this device, it is assumed that $T_J = T_A$.

ELECTRICAL CHARACTERISTICS

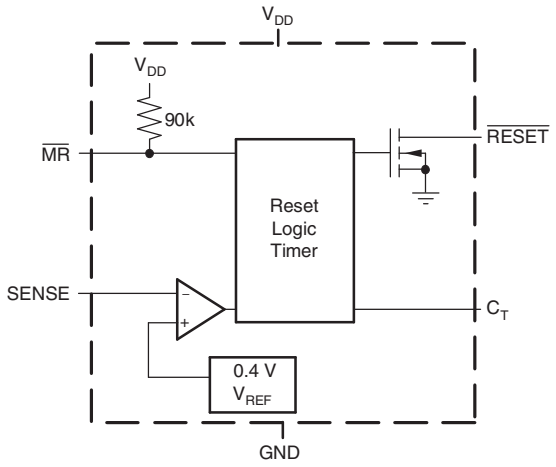
1.8 V ≤ V_{DD} ≤ 6.5 V, R_{LRESET} = 100 kΩ, C_{LRESET} = 50 pF, over operating temperature range (T_J = –40°C to 125°C) (unless otherwise noted), typical values at T_J = 25°C

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{DD}	Input supply range			1.8		6.5	V
I_{DD}	Supply current (into V_{DD} pin)	V_{DD} = 3.3 V, $\overline{RESET}$ not asserted, $\overline{MR}$, $\overline{RESET}$, C_T open			2.4	5	µA
		V_{DD} = 6.5 V, $\overline{RESET}$ not asserted, $\overline{MR}$, $\overline{RESET}$, C_T open			2.7	6	
V_{OL}	Low-level output voltage	1.3 V ≤ V_{DD} < 1.8 V, I_{OL} = 0.4 mA				0.3	V
		1.8 V ≤ V_{DD} ≤ 6.5 V, I_{OL} = 1 mA				0.4	
	Power-up reset voltage(1)	V_{OL} (max) = 0.2 V, I $\overline{RESET}$ = 15 µA				0.8	V
V_{IT}	Negative-going input threshold accuracy	TPS3808G01		–2	±1	+2	%
		V_{IT} ≤ 3.3 V		–1.5	±0.5	+1.5	
		3.3 V < V_{IT} ≤ 5 V		–2	±1	+2	
		V_{IT} ≤ 3.3 V	–40°C < T_J < 85°C	–1.25	±0.5	+1.25	
		3.3 V < V_{IT} ≤ 5 V		–1.5	±0.5	+1.5	
V_{HYS}	Hysteresis on V_{IT} pin	TPS3808G01			1.5	3	%V_{IT}
		–40°C < T_J < 85°C			1	2	
					1	2.5	
$R_{\overline{MR}}$	$\overline{MR}$ internal pullup resistance	V_{SENSE} = V_{IT}		70	90		kΩ
I_{SENSE}	Input current at SENSE pin	TPS3808G01		–25		25	nA
		V_{SENSE} = 6.5 V			1.7		µA
I_{OH}	$\overline{RESET}$ leakage current	V $\overline{RESET}$ = 6.5 V, $\overline{RESET}$ not asserted				300	nA
C_{IN}	Input capacitance, any pin	C_T pin	V_{IN} = 0 V to V_{DD}		5		pF
		Other pins	V_{IN} = 0 V to 6.5 V		5		
V_{IL}	$\overline{MR}$ logic low input			0		0.3 V_{DD}	V
V_{IH}	$\overline{MR}$ logic high input			0.7 V_{DD}		V_{DD}	V
t_w	Maximum transient duration	SENSE	V_{IH} = 1.05 V_{IT}, V_{IL} = 0.95 V_{IT}		20		µs
		$\overline{MR}$	V_{IH} = 0.7 V_{DD}, V_{IL} = 0.3 V_{DD}		0.001		
t_d	$\overline{RESET}$ delay time	C_T = Open	See timing diagram	12	20	28	ms
		C_T = V_{DD}		180	300	420	
		C_T = 100 pF		0.75	1.25	1.75	
		C_T = 180 nF		0.7	1.2	1.7	s
t_{pHL}	Propagation delay	$\overline{MR}$ to $\overline{RESET}$	V_{IH} = 0.7 V_{DD}, V_{IL} = 0.3 V_{DD}		150		ns
	High-level to low-level $\overline{RESET}$ delay	SENSE to $\overline{RESET}$	V_{IH} = 1.05 V_{IT}, V_{IL} = 0.95 V_{IT}		20		µs
θ_{JA}	Thermal resistance, junction to ambient				290		°C/W

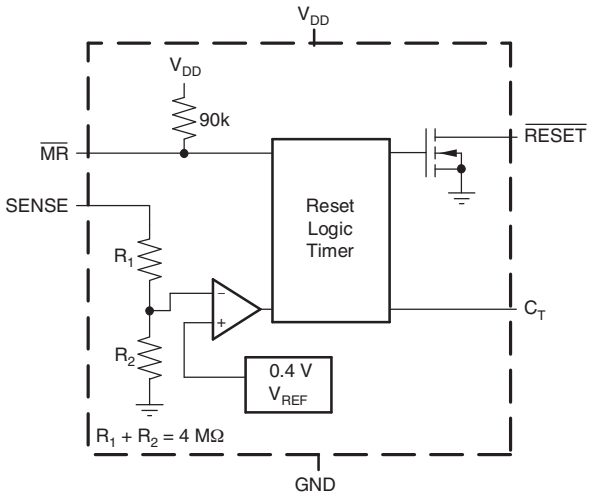
(1) Power-up reset voltage is the lowest supply voltage (V_{DD}) at which $\overline{RESET}$ becomes active ($t_{rise(VDD)}$ ≥ 15 µs/V).

FUNCTIONAL BLOCK DIAGRAMS

Adjustable-Voltage Version

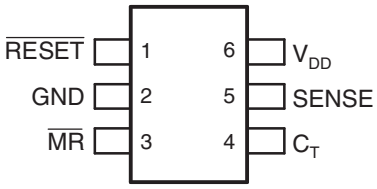


Fixed-Voltage Versions

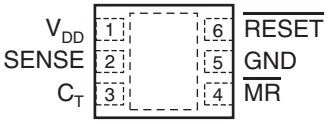


PIN ASSIGNMENTS

DBV (SOT-23) PACKAGE
(TOP VIEW)



DRV PACKAGE
(TOP VIEW)



PIN FUNCTIONS

PIN		DESCRIPTION
NAME	NO.	
$\overline{RESET}$	1	Reset. This is an open-drain output that is driven to a low impedance state when $\overline{RESET}$ is asserted (either the SENSE input is lower than the threshold voltage (V_{IT}) or the $\overline{MR}$ pin is set to a logic low). $\overline{RESET}$ remains low (asserted) for the reset period after both SENSE is above V_{IT} and $\overline{MR}$ is set to a logic high. A pullup resistor from 10 kΩ to 1 MΩ should be used on this pin, and allows the reset pin to attain voltages higher than V_{DD}.
GND	2	Ground
$\overline{MR}$	3	Manual reset. Driving this pin low asserts $\overline{RESET}$. $\overline{MR}$ is internally tied to V_{DD} by a 90-kΩ pullup resistor.
C_T	4	Reset period programming. Connecting this pin to V_{DD} through a 40-kΩ to 200-kΩ resistor or leaving it open results in fixed delay times (see *Electrical Characteristics*). Connecting this pin to a ground referenced capacitor ≥ 100 pF gives a user-programmable delay time.
SENSE	5	Voltage sense. This pin is connected to the voltage to be monitored. If the voltage at this terminal drops below the threshold voltage (V_{IT}), $\overline{RESET}$ is asserted.
V_{DD}	6	Supply voltage. It is good analog design practice to place a 0.1-μF ceramic capacitor close to this pin.

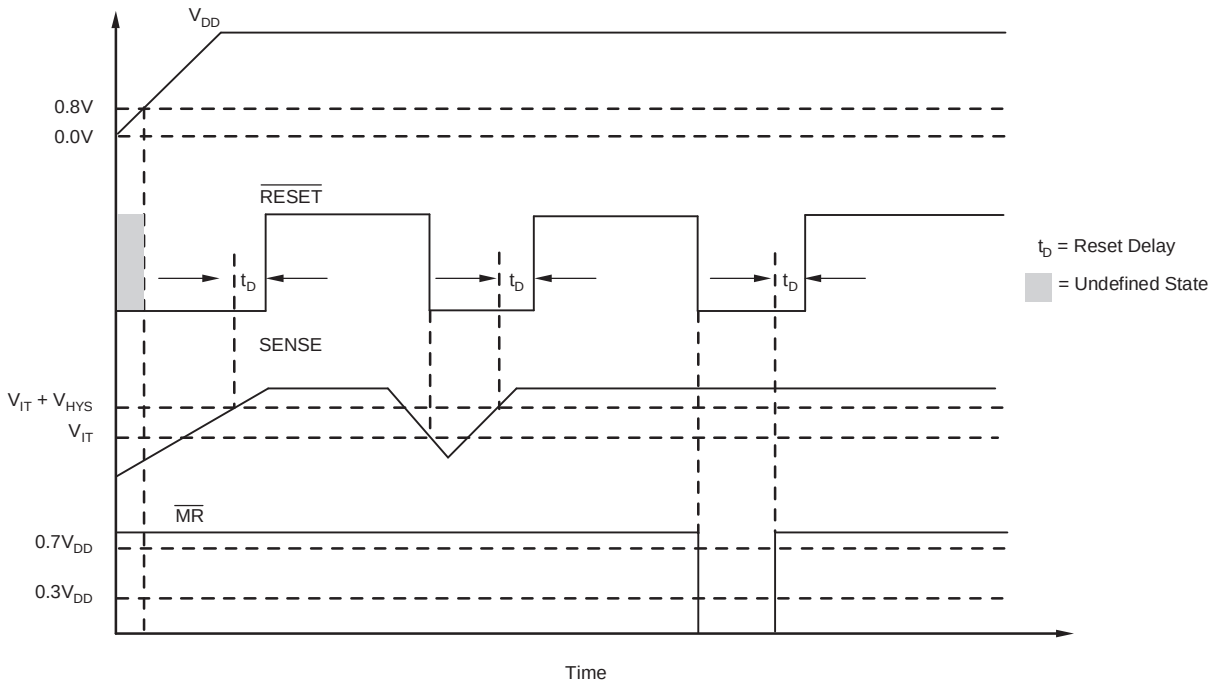


Figure 1. $\overline{MR}$ and SENSE Reset Timing Diagram

TRUTH TABLE

$\overline{MR}$	SENSE > V_{IT}	$\overline{RESET}$
L	0	L
L	1	L
H	0	L
H	1	H

TYPICAL CHARACTERISTICS

At T_J = 25°C, V_{DD} = 3.3 V, R_{LRESET} = 100 kΩ, and C_{LRESET} = 50 pF (unless otherwise noted)

SUPPLY CURRENT vs SUPPLY VOLTAGE

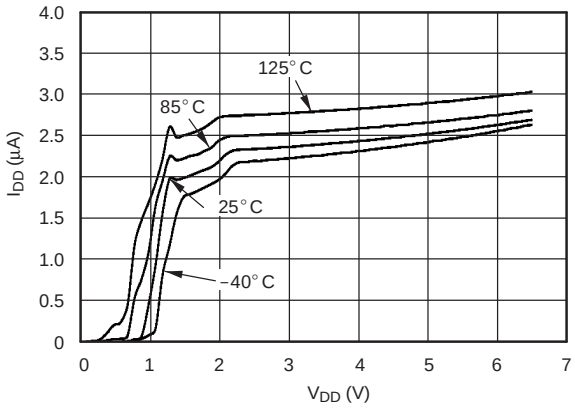


Figure 2.

$\overline{\text{RESET}}$ TIMEOUT PERIOD vs C_T

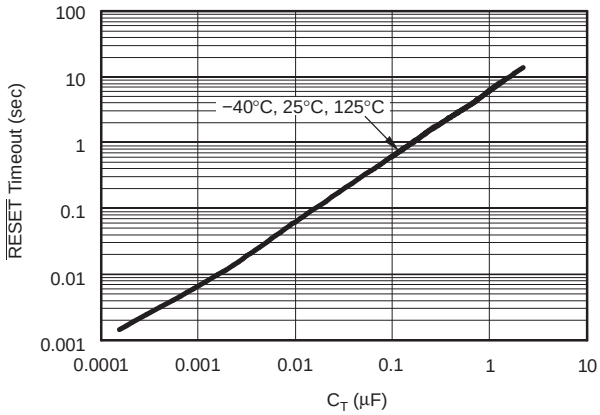


Figure 3.

NORMALIZED $\overline{\text{RESET}}$ TIMEOUT PERIOD vs TEMPERATURE (C_T = OPEN, C_T = V_{DD}, C_T = Any)

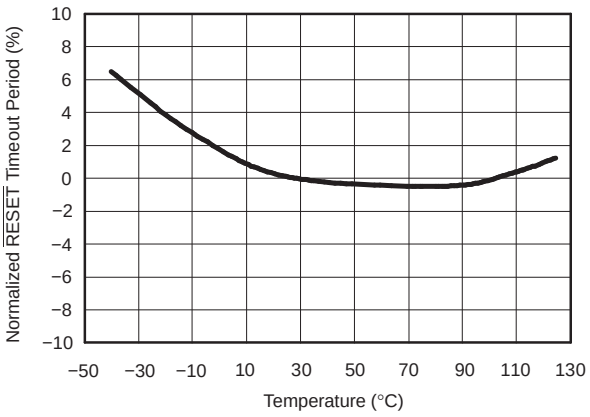


Figure 4.

MAXIMUM TRANSIENT DURATION AT SENSE vs SENSE THRESHOLD OVERDRIVE VOLTAGE

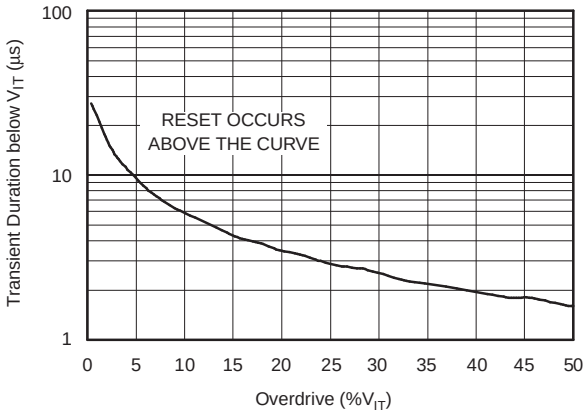


Figure 5.

TYPICAL CHARACTERISTICS (continued)

At T_J = 25°C, V_{DD} = 3.3 V, R_{LRESET} = 100 kΩ, and C_{LRESET} = 50 pF (unless otherwise noted)

NORMALIZED SENSE THRESHOLD VOLTAGE (V_{IT}) vs TEMPERATURE

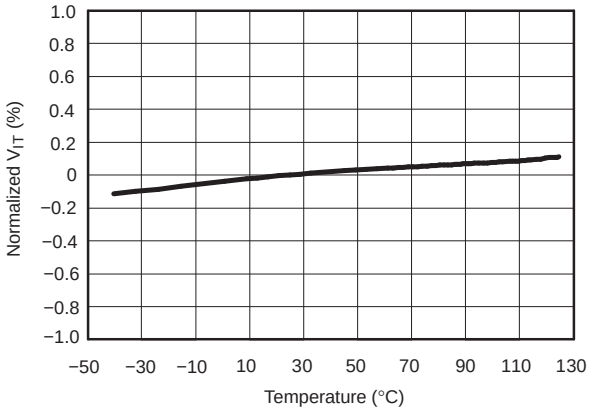


Figure 6.

LOW-LEVEL $\overline{\text{RESET}}$ VOLTAGE vs $\overline{\text{RESET}}$ CURRENT

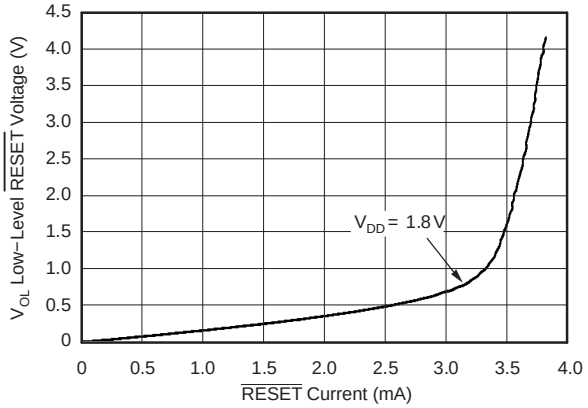


Figure 7.

LOW-LEVEL $\overline{\text{RESET}}$ VOLTAGE vs $\overline{\text{RESET}}$ CURRENT

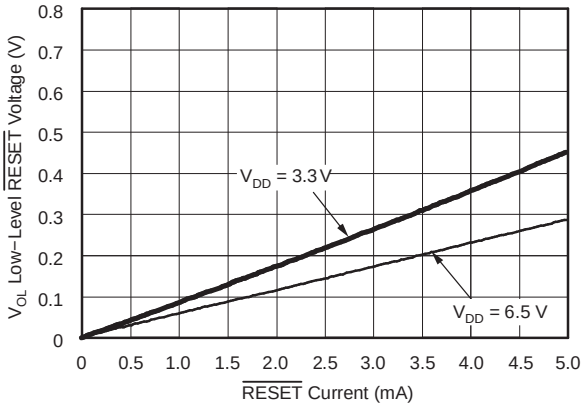


Figure 8.

DEVICE OPERATION

The TPS3808 microprocessor supervisory product family is designed to assert a $\overline{\text{RESET}}$ signal when either the SENSE pin voltage drops below V_{IT} or the manual reset ($\overline{\text{MR}}$) is driven low. The $\overline{\text{RESET}}$ output remains asserted for a user-adjustable time after both the manual reset ($\overline{\text{MR}}$) and SENSE voltages return above the respective thresholds. A broad range of voltage threshold and reset delay time adjustments are available, allowing these devices to be used in a wide array of applications. Reset threshold voltages can be factory-set from 0.82 V to 3.3 V or from 4.4 V to 5.0 V, while the TPS3808G01 can be set to any voltage above 0.405 V using an external resistor divider. Two preset delay times are also user-selectable: connecting the C_T pin to V_{DD} results in a 300-ms reset delay, while leaving the C_T pin open yields a 20-ms reset delay. In addition, connecting a capacitor between C_T and GND allows the designer to select any reset delay period from 1.25 ms to 10 s.

SENSE Input

The SENSE input provides a terminal at which any system voltage can be monitored. If the voltage on this pin drops below V_{IT}, $\overline{\text{RESET}}$ is asserted. The comparator has a built-in hysteresis to ensure smooth $\overline{\text{RESET}}$ assertions and deassertions. It is good analog design practice to put a 1-nF to 10-nF bypass capacitor on the SENSE input to reduce sensitivity to transients and layout parasitics.

The TPS3808G01 can be used to monitor any voltage rail down to 0.405 V using the circuit shown in Figure 9.

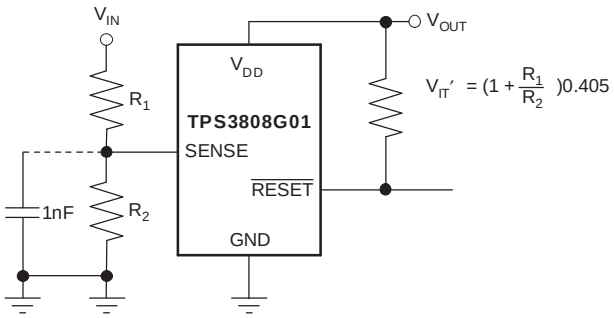


Figure 9. Using the TPS3808G01 to Monitor a User-Defined Threshold Voltage

Manual Reset ($\overline{\text{MR}}$) Input

The manual reset ($\overline{\text{MR}}$) input allows a processor or other logic circuits to initiate a reset. A logic low (0.3 V_{DD}) on $\overline{\text{MR}}$ causes $\overline{\text{RESET}}$ to assert. After $\overline{\text{MR}}$ returns to a logic high and SENSE is above its reset threshold, $\overline{\text{RESET}}$ is deasserted after the user-defined reset delay expires. Note that $\overline{\text{MR}}$ is internally tied to V_{DD} using a 90-kΩ resistor, so this pin can be left unconnected if $\overline{\text{MR}}$ is not used.

Refer to Figure 10 for how $\overline{\text{MR}}$ can be used to monitor multiple system voltages. Note that if the logic signal driving $\overline{\text{MR}}$ does not go fully to V_{DD}, there will be some additional current draw into V_{DD} as a result of the internal pullup resistor on $\overline{\text{MR}}$. To minimize current draw, a logic-level FET can be used as shown in Figure 11.

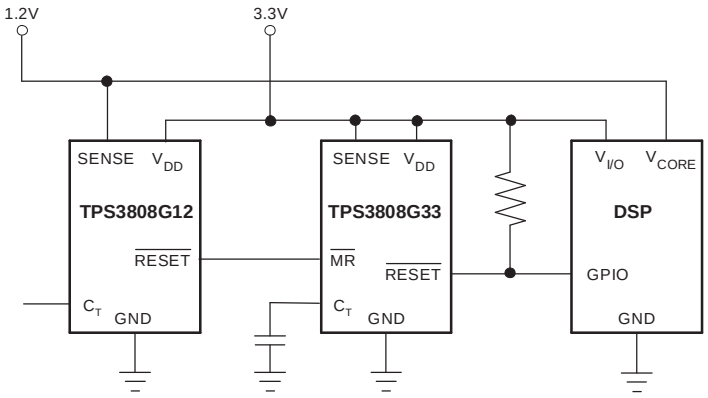


Figure 10. Using $\overline{\text{MR}}$ to Monitor Multiple System Voltages

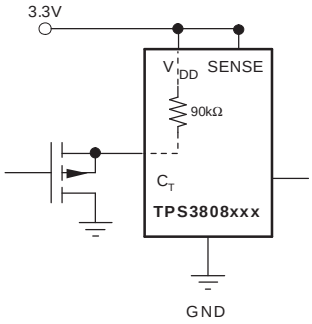


Figure 11. Using an External MOSFET to Minimize I_{DD} When $\overline{MR}$ Signal Does Not Go to V_{DD}

Selecting the Reset Delay Time

The TPS3808 has three options for setting the $\overline{RESET}$ delay time as shown in Figure 12. Figure 12a shows the configuration for a fixed 300-ms typical delay time by tying C_T to V_{DD}; a resistor from 40 kΩ to 200 kΩ must be used. Supply current is not affected by the choice of resistor. Figure 12b shows a fixed 20-ms delay time by leaving the C_T pin open. Figure 12c shows a ground referenced capacitor connected to C_T for a user-defined program time between 1.25 ms and 10 s.

The capacitor C_T should be ≥100 pF nominal value in order for the TPS3808 to recognize that the capacitor is present. The capacitor value for a given delay time can be calculated using the following equation:

$$C_T\,(nF) = \left[t_D\,(s) - 0.5 \times 10^{-3}\,(s)\right] \times 175 \quad (1)$$

The reset delay time is determined by the time it takes an on-chip precision 220-nA current source to charge the external capacitor to 1.23 V. When a $\overline{RESET}$ is asserted, the capacitor is discharged. When the $\overline{RESET}$ conditions are cleared, the internal current source is enabled and begins to charge the external capacitor. When the voltage on this capacitor reaches 1.23 V, $\overline{RESET}$ is deasserted. Note that a low-leakage type capacitor such as a ceramic should be used and that stray capacitance around this pin may cause errors in the reset delay time.

Immunity to SENSE Pin Voltage Transients

The TPS3808 is relatively immune to short negative transients on the SENSE pin. Sensitivity to transients is dependent on threshold overdrive, as shown in the *Maximum Transient Duration at Sense vs Sense Threshold Overdrive Voltage* graph (Figure 5) in the Typical Characteristics section.

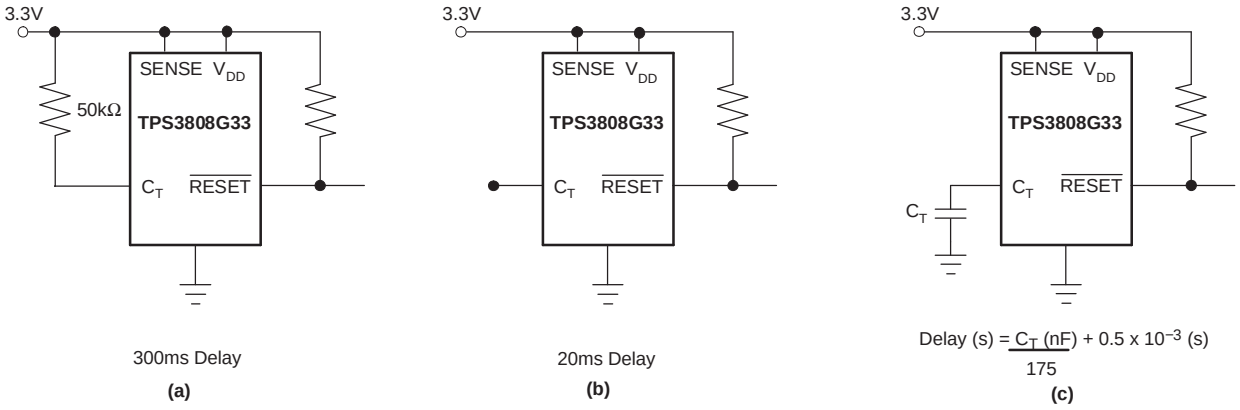


Figure 12. Configuration Used to Set the $\overline{RESET}$ Delay Time

REVISION HISTORY

Changes from Revision G (November, 2010) to Revision H	Page
• Changed I_{SENSE} from µA to nA	3

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/ Ball Finish	MSL Peak Temp (3)	Samples (Requires Login)
TPS3808G01QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
TPS3808G01QDRVRQ1	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
TPS3808G125QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
TPS3808G12QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
TPS3808G18QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
TPS3808G30QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
TPS3808G33QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
TPS3808G50QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

OTHER QUALIFIED VERSIONS OF TPS3808G01-Q1, TPS3808G12-Q1, TPS3808G125-Q1, TPS3808G18-Q1, TPS3808G30-Q1, TPS3808G33-Q1, TPS3808G50-Q1 :

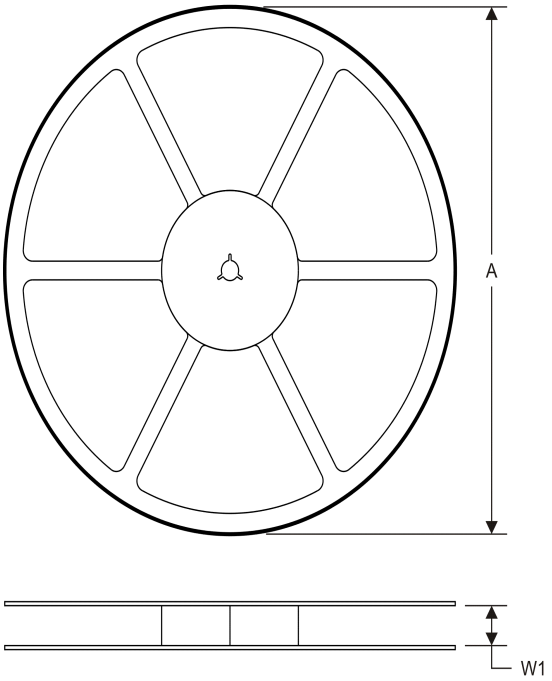
- Catalog: TPS3808G01, TPS3808G12, TPS3808G125, TPS3808G18, TPS3808G30, TPS3808G33, TPS3808G50

NOTE: Qualified Version Definitions:

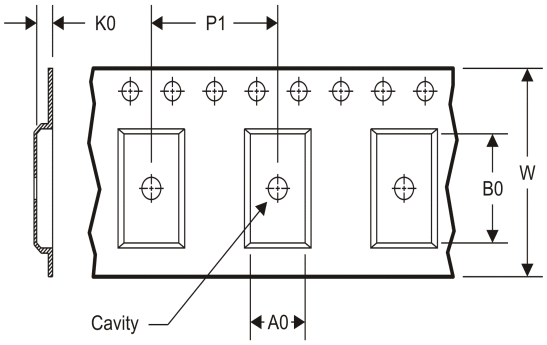
- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



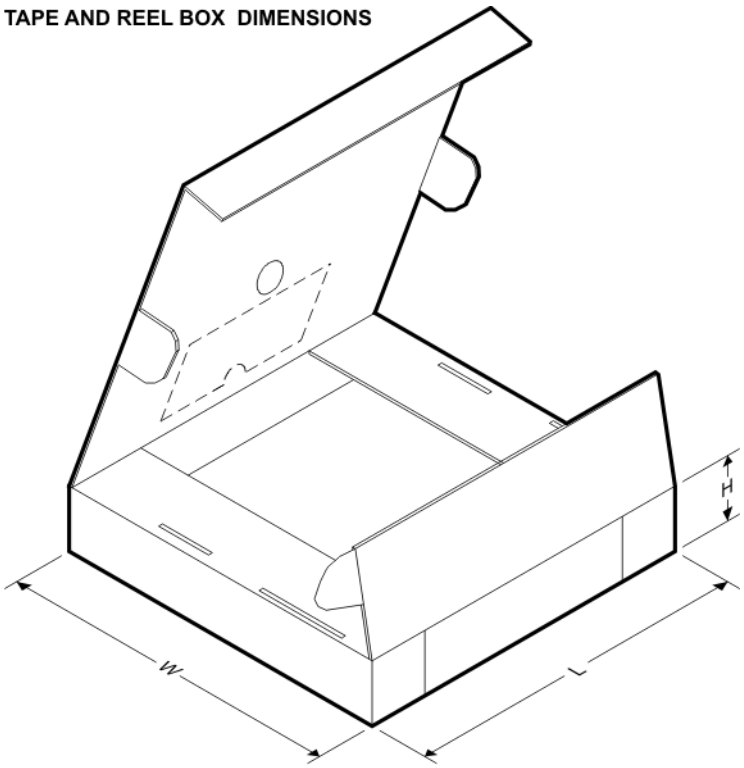
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS3808G01QDRVRQ1	SON	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS3808G125QDBVRQ1	SOT-23	DBV	6	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

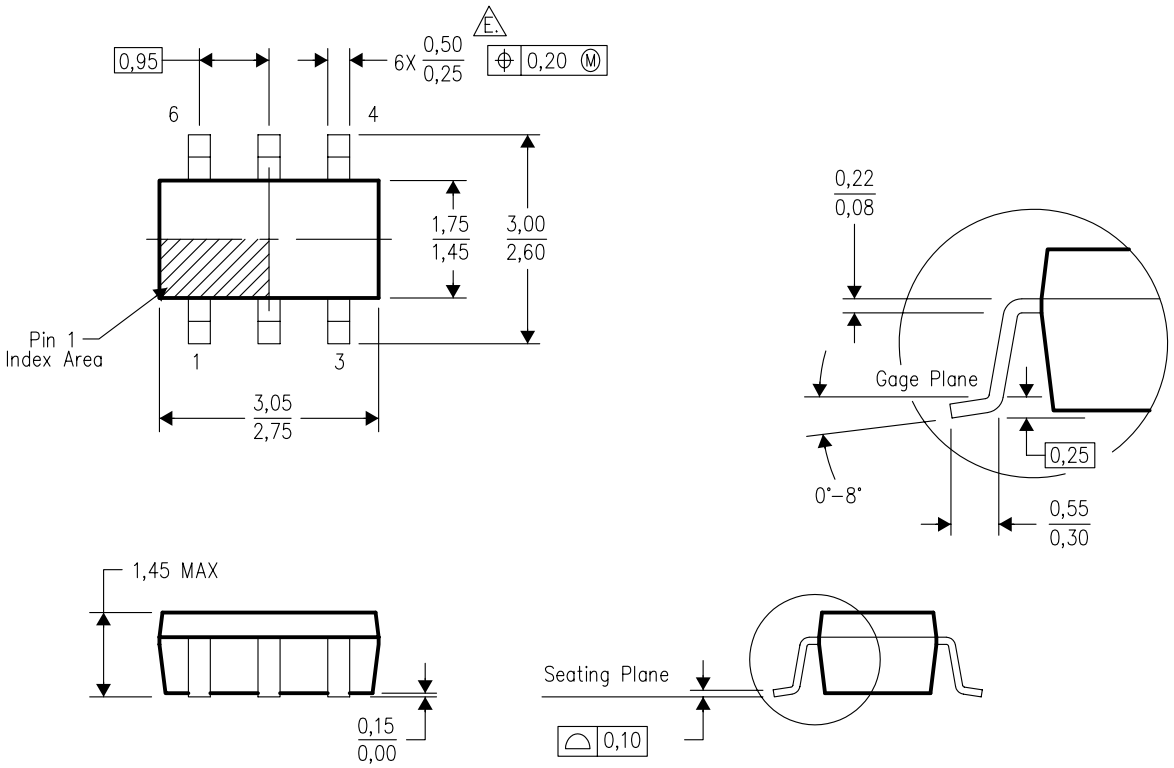
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS3808G01QDRVRQ1	SON	DRV	6	3000	210.0	185.0	35.0
TPS3808G125QDBVRQ1	SOT-23	DBV	6	3000	203.0	203.0	35.0

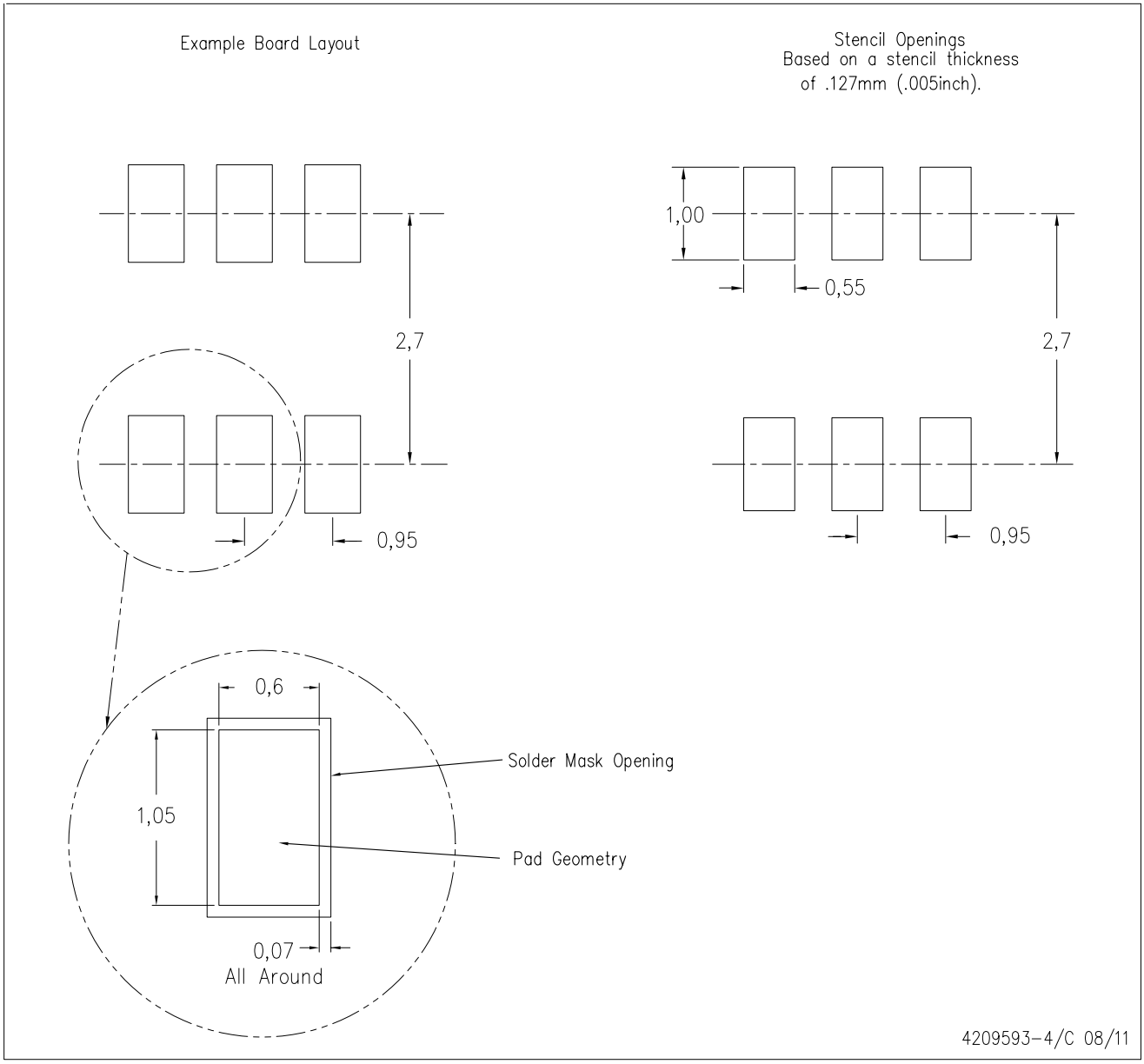
DBV (R–PDSO–G6) PLASTIC SMALL–OUTLINE PACKAGE



4073253–5/K 03/2006

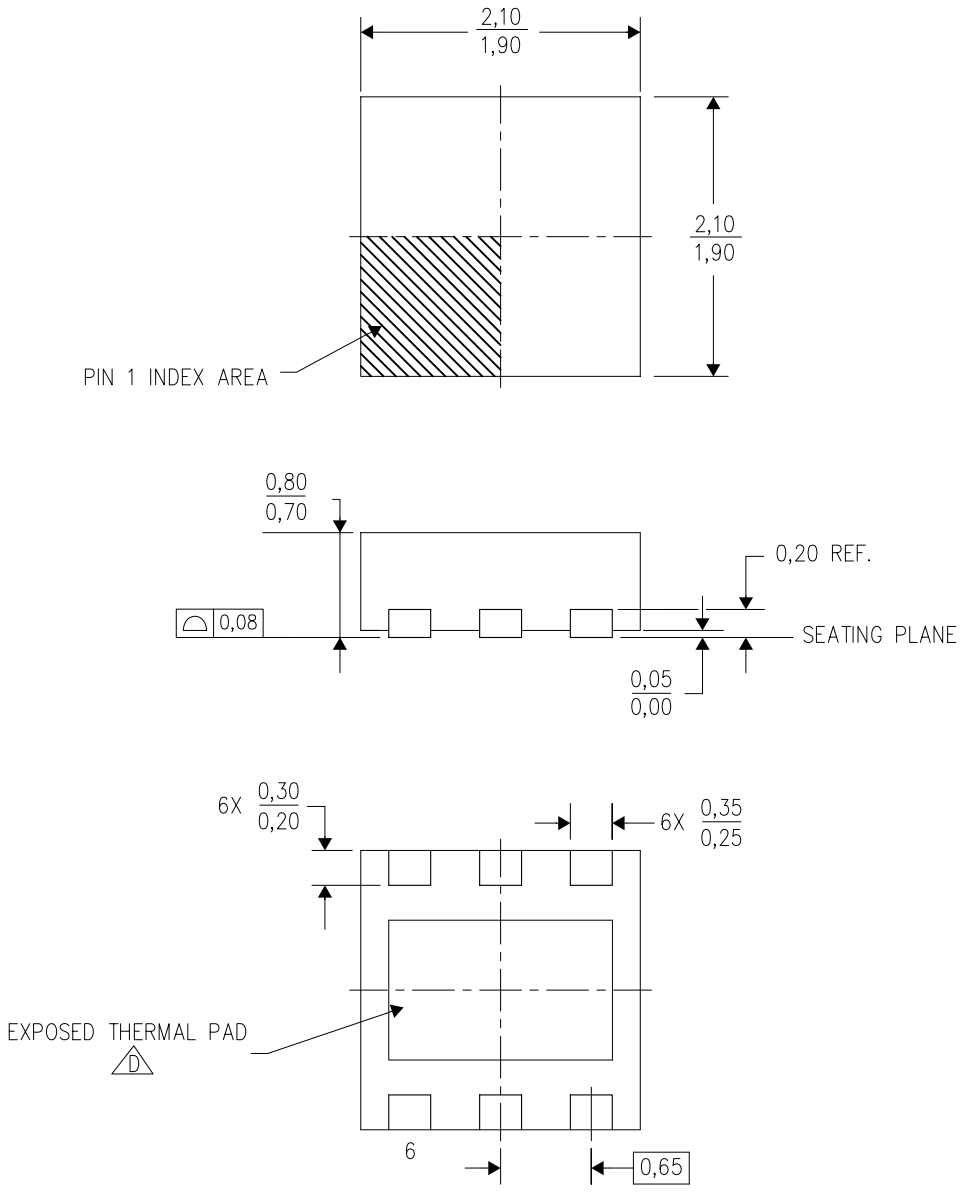
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
E. Falls within JEDEC MO–178 Variation AB, except minimum lead width.

DBV (R-PDSO-G6) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. Publication IPC-7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

DRV (S–PWSON–N6) PLASTIC SMALL OUTLINE NO–LEAD



4206925/E 10/10

NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Small Outline No–Lead (SON) package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.

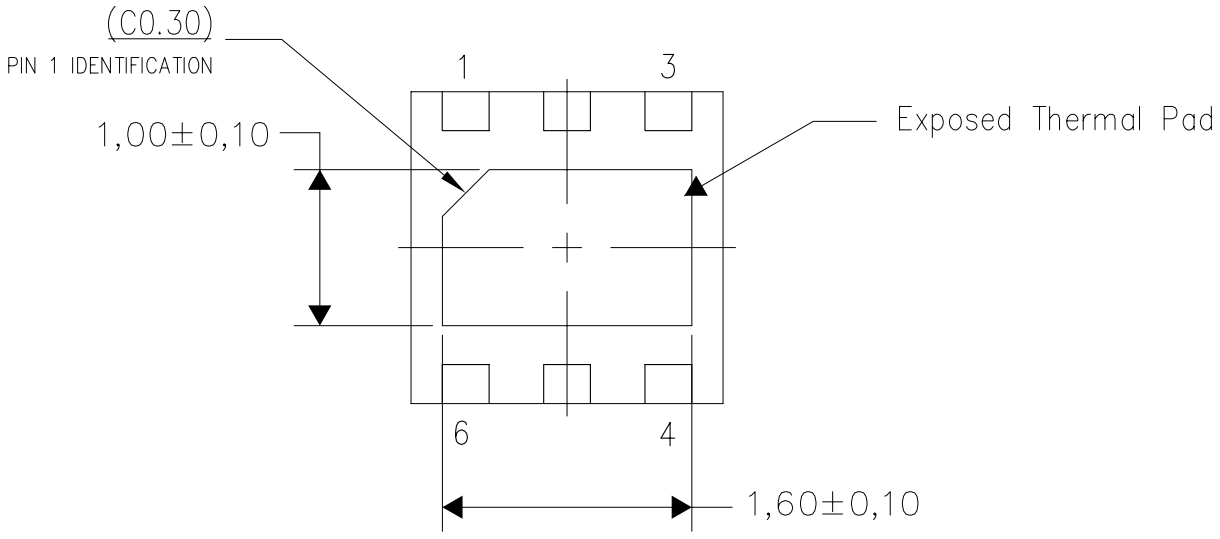
DRV (S–PWSON–N6) PLASTIC SMALL OUTLINE NO–LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No–Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



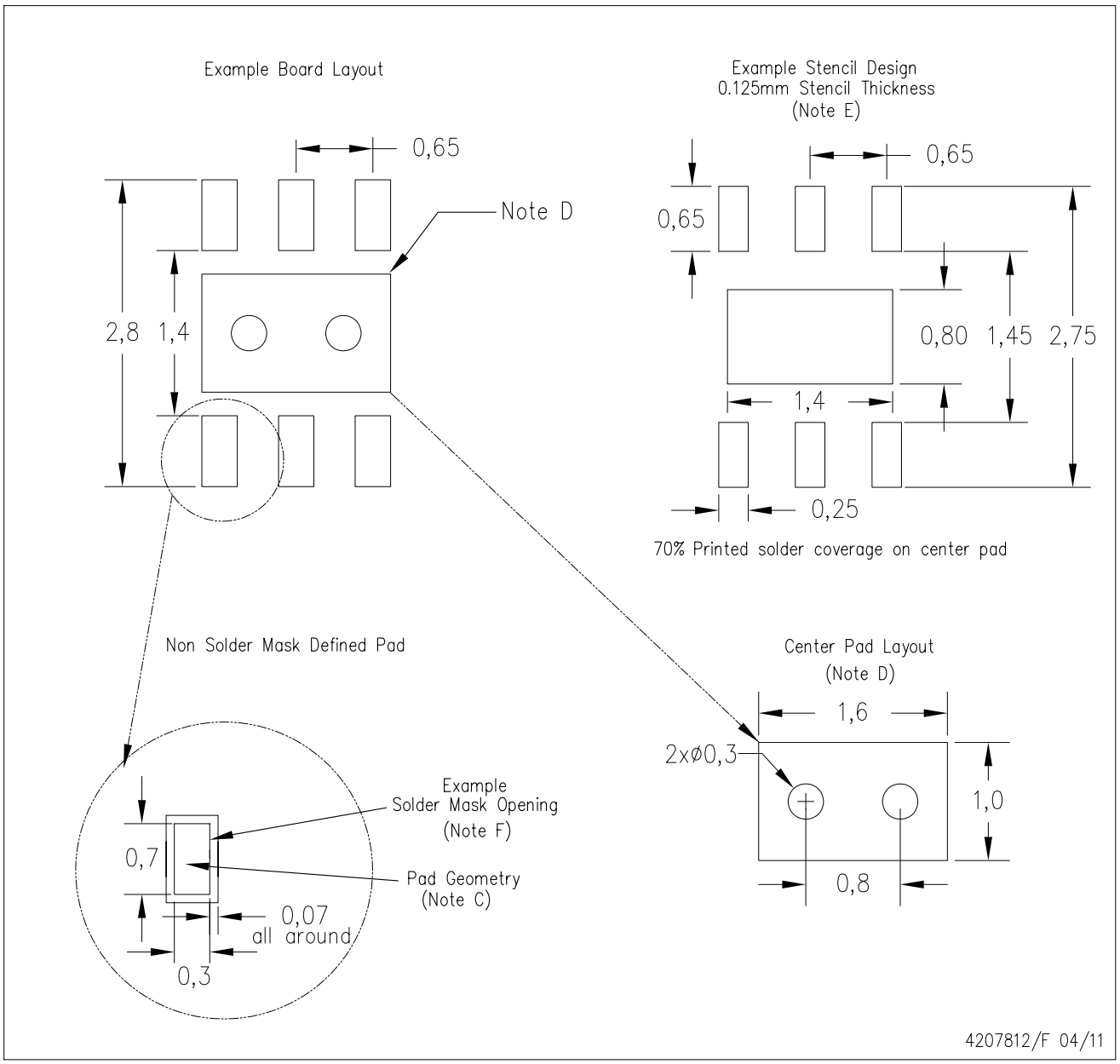
Bottom View

Exposed Thermal Pad Dimensions

4206926–2/L 11/11

NOTE: A. All linear dimensions are in millimeters

DRV (S–PWSON–N6) PLASTIC SMALL OUTLINE NO–LEAD



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
F. Customers should contact their board fabrication site for solder mask tolerances.